TOSHIBA Diode Silicon Epitaxial Schottky Barrier Type

1SS419

High-Speed Switching Applications

• Small package

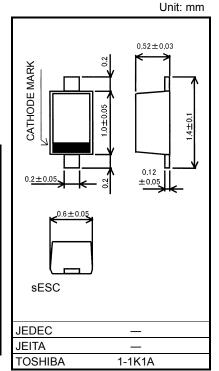
• Low forward voltage: V_{F (3)} = 0.56 V (typ.)

• Low reverse current: I_R = 5 μA (max)

Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Maximum (peak) reverse voltage	V_{RM}	45	V
Reverse voltage	V _R	40	V
Maximum (peak) forward current	I _{FM}	200	mA
Average forward current	I _O	100	mA
Surge current (10 ms)	I _{FSM}	1	Α
Power dissipation	P*	100	mW
Junction temperature	Tj	125	°C
Storage temperature range	T _{stg}	-55~125	°C
Operating temperature range	T _{opr}	-40~100	°C

Mounted on a glass-epoxy circuit board of 20×20 mm, pad dimensions of 4×4 mm.

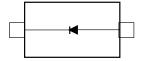


Weight: 0.0011 g (typ.)

Electrical Characteristics (Ta = 25°C)

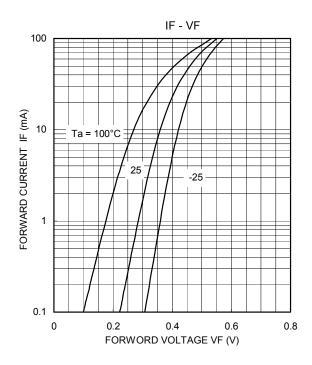
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Forward voltage	V _{F (1)}	I _F = 1 mA	_	0.28	_	V
	V _{F (2)}	I _F = 10 mA	_	0.36	_	
	V _{F (3)}	I _F = 50 mA	_	0.56	0.62	
Reverse current	I _R	V _R = 40 V	_	_	5	μΑ
Total capacitance	C _T	V _R = 0, f = 1 MH _z	_	15	_	pF

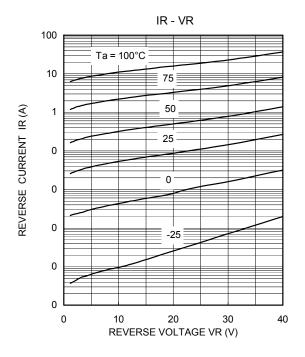
Equivalent Circuit (Top View)

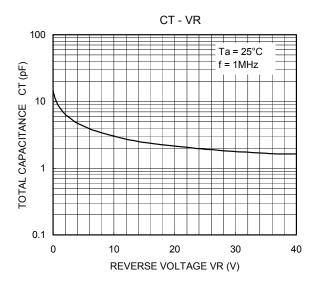


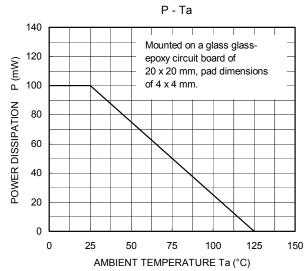
Marking











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